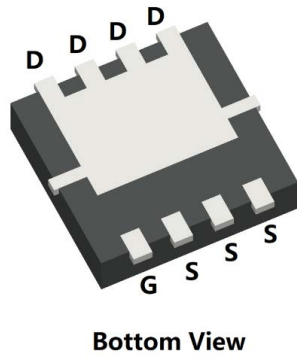
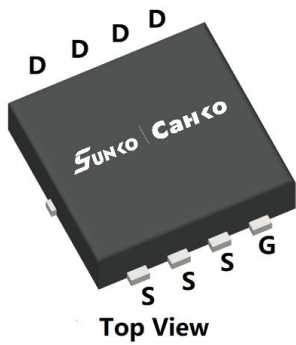
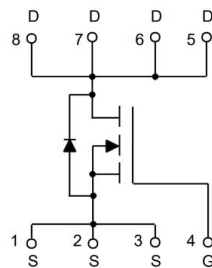


P-Channel Enhancement Mode Field Effect Transistor



PDFN3333-8L



Product Summary

- V_{DS} -100V
- I_D -8A
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) <200m Ω
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) <235m Ω
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Power switching application
- Uninterruptible power supply
- DC-DC convertor

■ Absolute Maximum Ratings ($T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter			Symbol	Limit	Unit
Drain-source Voltage			V _{DS}	-100	V
Gate-source Voltage			V _{GS}	±20	V
Continuous Drain Current (Note 1,2)	Steady-State	T _A =25℃	I _D	-2	A
		T _A =100℃		-1.2	
Continuous Drain Current (Note 1,3)	Steady-State	T _C =25℃		-8	
		T _C =100℃		-5	
Pulsed Drain Current	T _C =25℃ , t _p =100μs		I _{DM}	-25	A
Avalanche energy	V _G =-10V, R _G =25Ω, L=0.5mH, I _{AS} =-10.5A		EAS	27.56	mJ
Total Power Dissipation (Note 1,2)	Steady-State	T _A =25℃	P _D	1.78	W
		T _A =100℃		0.71	
Total Power Dissipation (Note 1,3)	Steady-State	T _C =25℃		29.7	
		T _C =100℃		11.9	
Junction and Storage Temperature Range			T _J ,T _{STG}	-55～+150	℃

■ Thermal resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	Steady-State	$R_{\theta JA}$	56	70	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Case	Steady-State	$R_{\theta JC}$	3.5	4.2	

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SCQ200P10AJ	F1	Q200P10	5000	10000	100000	13" reel

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =-250μA	-100	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V, V _{GS} =0V	-	-	-1	μA
		V _{DS} =-100V, V _{GS} =0V, T _j =150°C	-	-	-100	
Gate-Body Leakage Current	I _{GSS}	V _{GS} = ±20V, V _{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =-250μA	-1.1	-1.6	-2.1	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-5A	-	155	200	mΩ
		V _{GS} =-4.5V, I _D =-3A	-	170	235	
Diode Forward Voltage	V _{SD}	I _S =-5A, V _{GS} =0V	-	-	-1.2	V
Gate resistance	R _G	f=1MHz	-	18	-	Ω
Maximum Body-Diode Continuous Current	I _S		-	-	-8	A
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{DS} =-50V, V _{GS} =0V, f=1MHz	-	1370	-	pF
Output Capacitance	C _{oss}		-	34	-	
Reverse Transfer Capacitance	C _{rss}		-	29	-	
Switching Parameters						
Total Gate Charge	Q _g	V _{GS} =-10V, V _{DS} =-50V, I _D =-0.5A	-	18	-	nC
Gate-Source Charge	Q _{gs}		-	2	-	
Gate-Drain Charge	Q _{gd}		-	2	-	
Reverse Recovery Charge	Q _{rr}	I _F =-0.5A, di/dt=100A/us	-	23.7	-	nC
Reverse Recovery Time	t _{rr}		-	20.8	-	ns
Turn-on Delay Time	t _{D(on)}	V _{GS} =-10V, V _{DD} =-50V, I _D =-0.5A R _{GEN} =2.7Ω	-	6.5	-	ns
Turn-on Rise Time	t _r		-	23.6	-	
Turn-off Delay Time	t _{D(off)}		-	131	-	
Turn-off fall Time	t _f		-	133	-	

Note:

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
2. The value of R_{θJA} is measured with the device mounted on the 40mm*40mm*1.1mm single layer FR-4 PCB board with 1 in² pad of 2oz. Copper, in the still air environment with T_A =25°C. The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
3. Thermal resistance from junction to soldering point (on the exposed drain pad).

■ Typical Electrical and Thermal Characteristics Diagrams

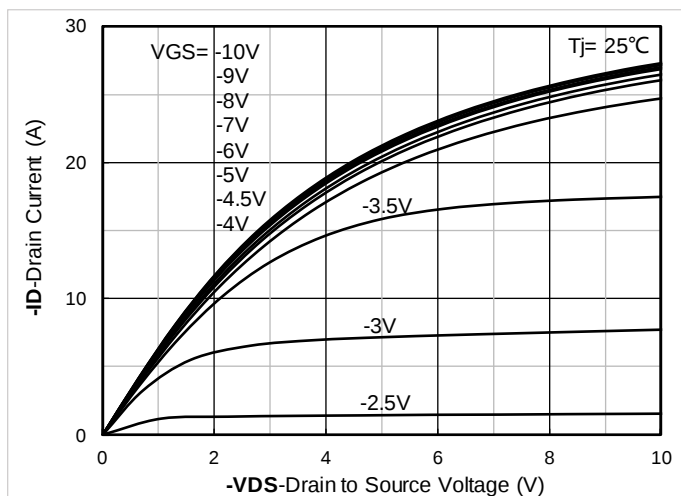


Figure 1. Output Characteristics

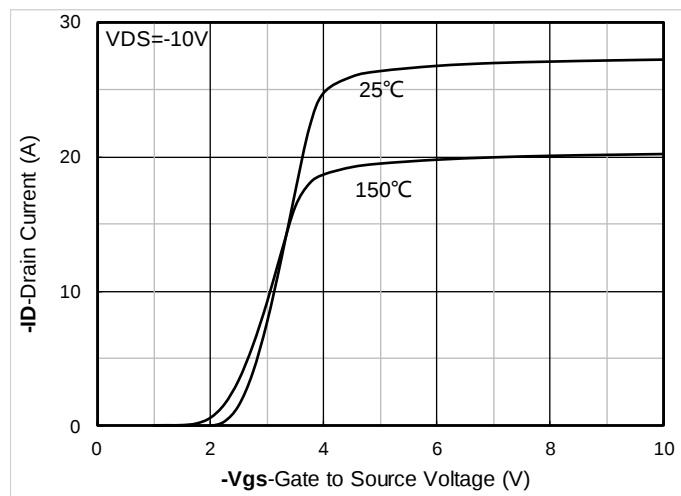


Figure 2. Transfer Characteristics

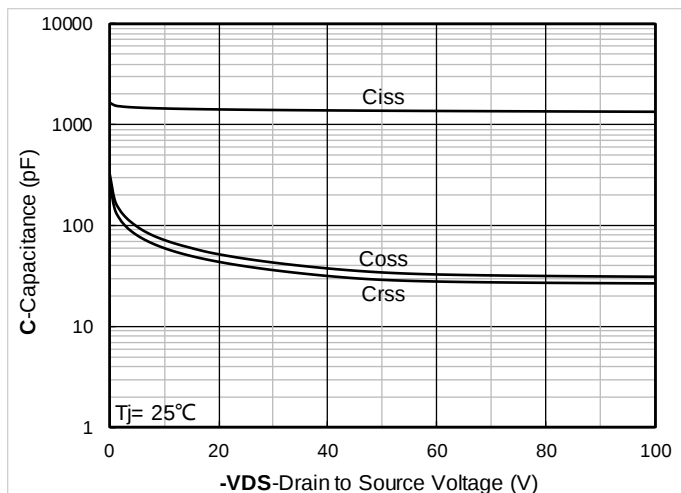


Figure 3. Capacitance Characteristics

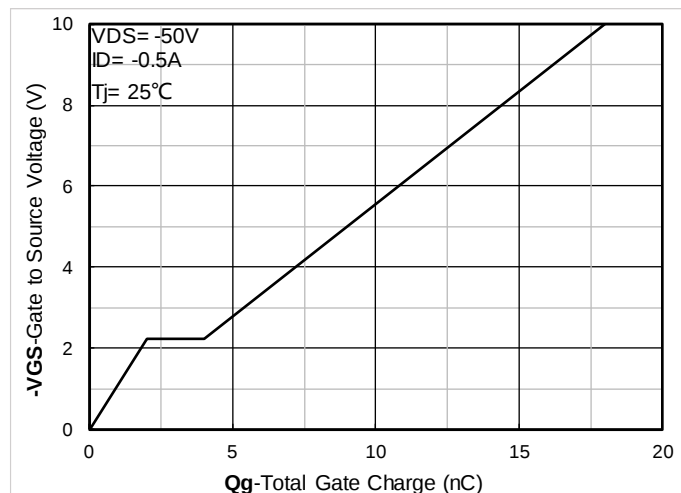


Figure 4. Gate Charge

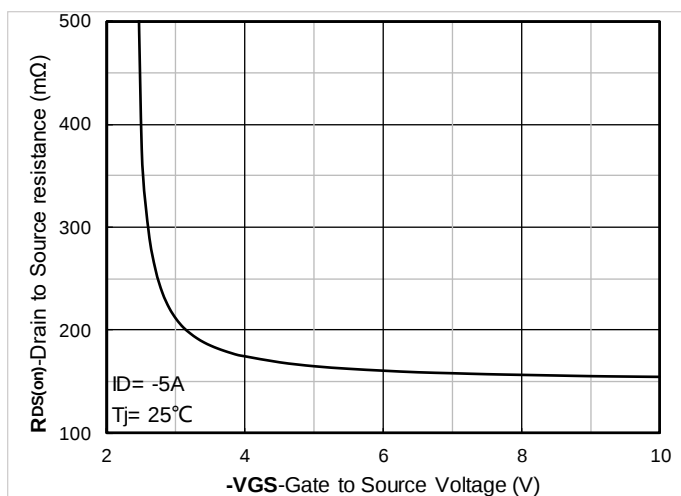


Figure 5. On-Resistance vs Gate to Source Voltage

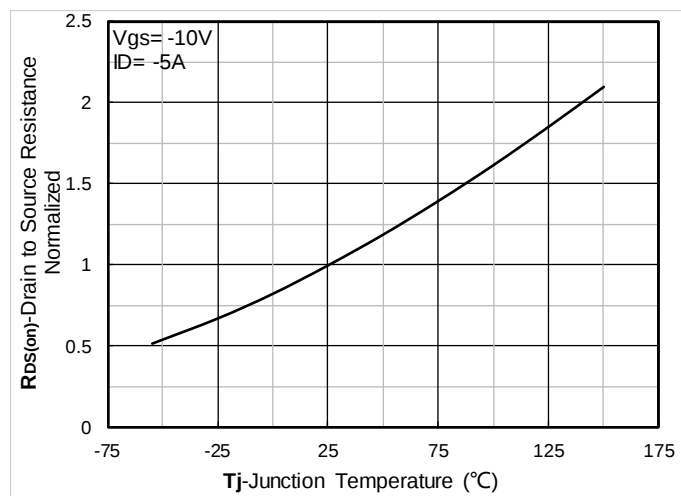


Figure 6. Normalized On-Resistance

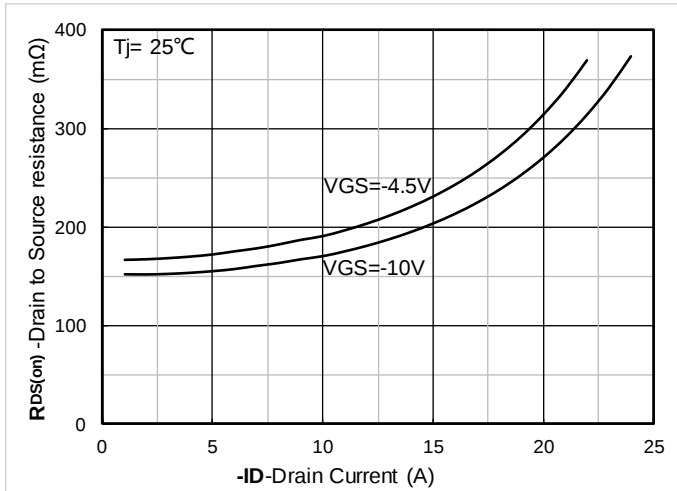


Figure 7. $R_{DS(on)}$ VS Drain Current

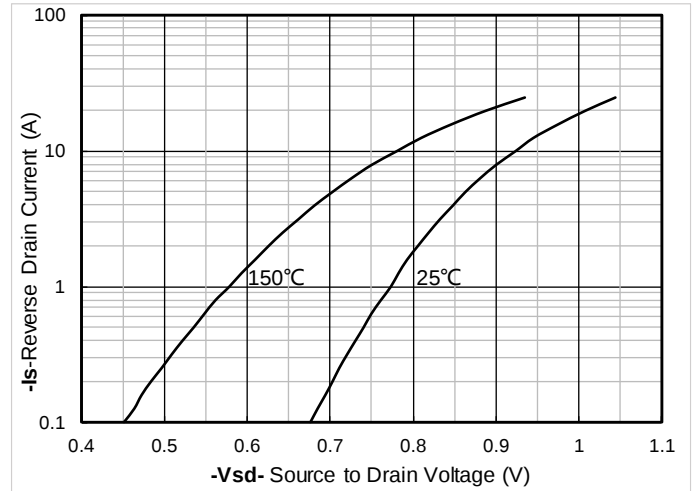


Figure 8. Forward characteristics of reverse diode

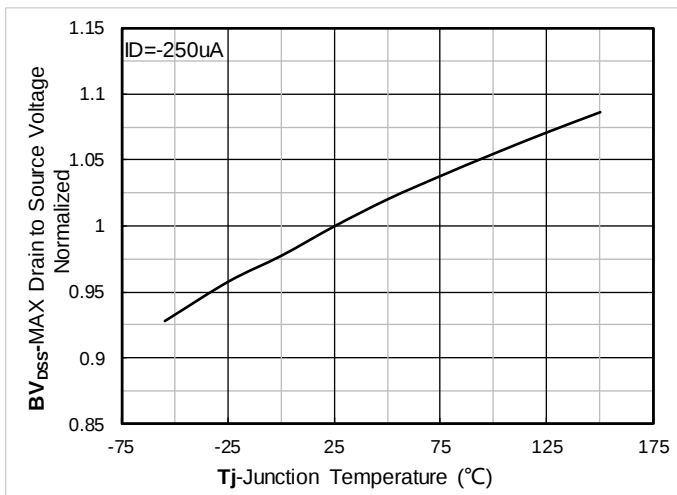


Figure 9. Normalized breakdown voltage

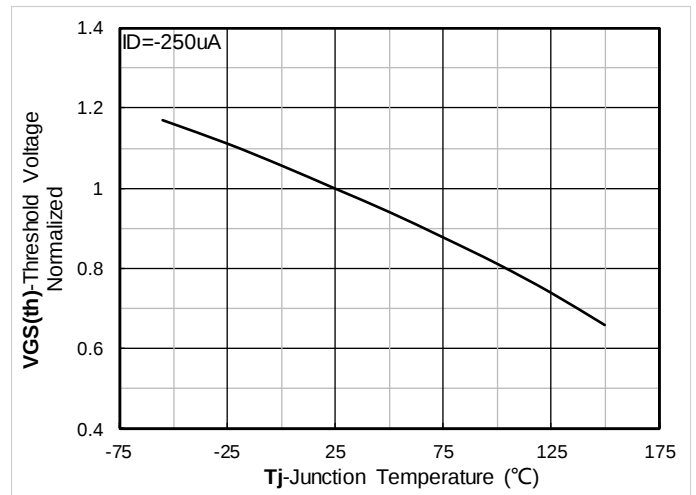


Figure 10. Normalized Threshold voltage

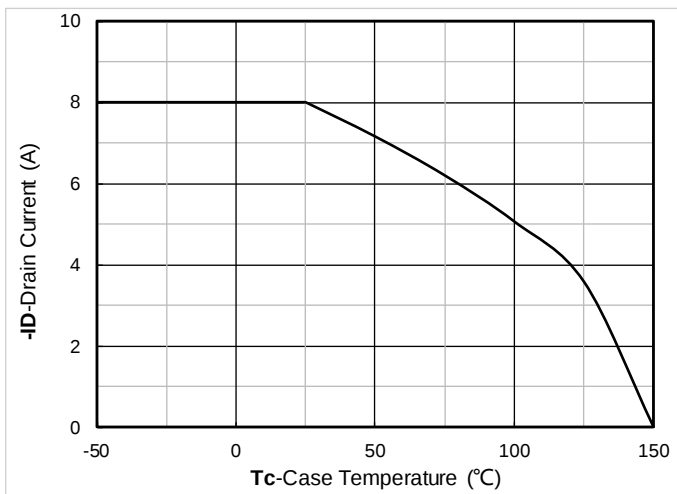


Figure 11. Current dissipation

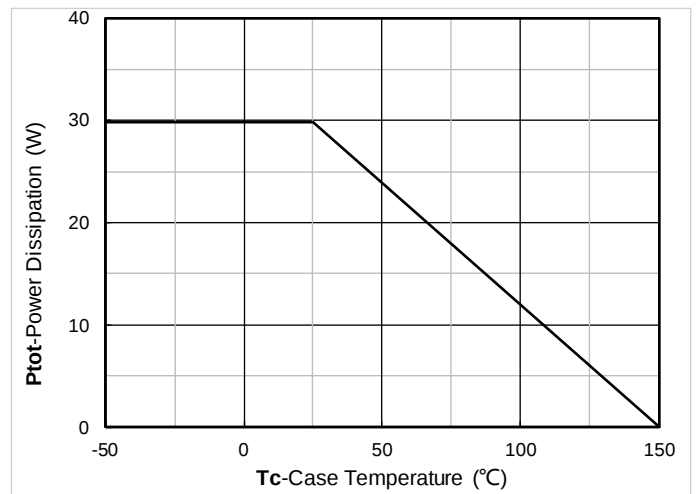


Figure 12. Power dissipation

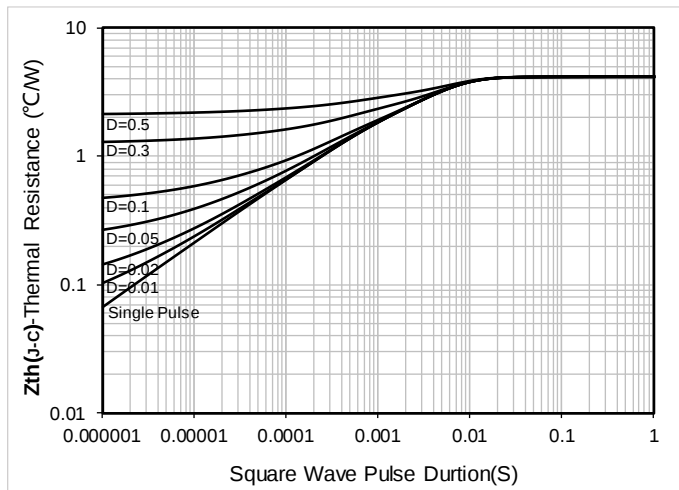


Figure 13. Maximum Transient Thermal Impedance

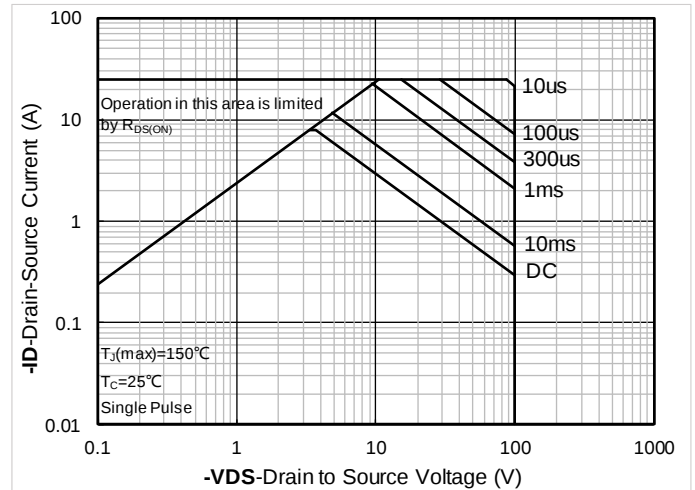
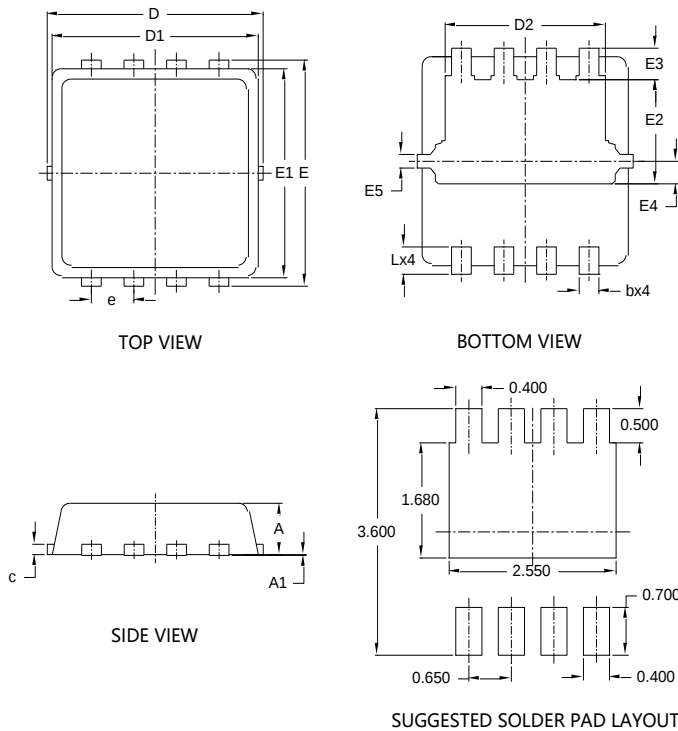


Figure 14. Safe Operation Area

■ PDFN3333-8L-B-0.75MM Package information



SYMBOL	DIMENSIONS			
	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.028	0.033	0.700	0.850
A1	0.000	0.002	0.000	0.050
b	0.008	0.016	0.200	0.400
c	0.004	0.010	0.100	0.250
D	0.124	0.136	3.150	3.450
D1	0.118	0.130	3.000	3.300
D2	0.089	0.104	2.250	2.650
E	0.124	0.136	3.150	3.450
E1	0.114	0.126	2.900	3.200
E2	0.052	0.068	1.320	1.720
E3	0.011	0.026	0.280	0.650
E4	0.013 REF		0.330 REF	
E5	0.008 REF		0.200 REF	
e	0.026 BSC		0.650 BSC	
L	0.012	0.020	0.300	0.500

NOTE:
 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
 2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
 3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

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